

## **Vishay Semiconductors**

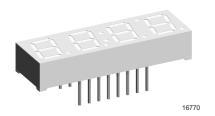
# **Clock Display**

### **Description**

Four digit Display, with 10 mm digit charactersize. Designed as clock Display with active colon between digit two and three.

### **Features**

- · High efficient AllnGAP technology
- Dark surface, white segments
- Common anode (TDC.1050m)
- Common cathode (TDC.1060m)
- · Recommended viewing distance up to 7 meter
- · Multiplex mode



## **Applications**

Clock modules for Video/Audioequipment, Instrumentation, Set Top Boxes

### **Parts Table**

Part	Color, Luminous Intensity	Circuitry
TDCG1050m	Green, $I_V = (2.8 \text{ to } 4.0) \text{ mcd}$	Common anode
TDCG1060m	Green, I <sub>V</sub> = (2.8 to 4.0) mcd	Common cathode
TDCR1050m	Super red, I <sub>V</sub> = (4.0 to 6.0) mcd	Common anode
TDCR1060m	Super red, I <sub>V</sub> = (4.0 to 6.0) mcd	Common cathode
TDCY1050m	Super Yellow, I <sub>V</sub> = (4.0 to 8.0) mcd	Common anode
TDCY1060m	Super Yellow, I <sub>V</sub> = (4.0 to 8.0) mcd	Common cathode

### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

TDCG1050m/ TDCG1060m, TDCR1050m/ TDCR1060m, TDCY1050m/ TDCY1060m,

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	25	mA
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature		T <sub>sd</sub>	260 ± 5	°C
Power dissipation		P <sub>V</sub>	60	mW
Peak forward current	(Duty 1/10 @ 1kHz)	I <sub>F</sub> (Peak)	160	mA

# TDCG / R / Y10..m

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# **Optical and Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

## Super red

#### TDCR1050m/TDCR1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I <sub>F</sub> = 2 mA	TDCR1050m	Ι <sub>V</sub>		1.5		mcd
segment 1)							
		TDCR1060m	$I_{V}$		1.5		mcd
	I <sub>F</sub> = 10 mA	TDCR1050m	I <sub>V</sub>	4.0	6.0		mcd
		TDCR1060m	I <sub>V</sub>	4.0	6.0		mcd
Luminous intensity of colon	I <sub>F</sub> = 2 mA	TDCR1050m	I <sub>V</sub>		0.4		mcd
		TDCR1060m	I <sub>V</sub>		0.4		mcd
	I <sub>F</sub> = 10 mA	TDCR1050m	I <sub>V</sub>	0.5	0.8		mcd
		TDCR1060m	I <sub>V</sub>	0.5	0.8		mcd
Dominant wavelength	I <sub>F</sub> = 20 mA		$\lambda_{d}$		631		nm
Peak wavelength	I <sub>F</sub> = 20 mA		$\lambda_{p}$		639		nm
Spectral bandwidth	I <sub>F</sub> = 20 mA		Δλ		20		nm
Forward voltage	I <sub>F</sub> = 20 mA		V <sub>F</sub>		2.0	2.4	V
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>			10	μΑ

Note<sup>1)</sup>  $I_{Vmin}$  and  $I_{V}$  groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is  $\geq$  0.5, excluding decimal points and colon.

### Yellow

#### TDCY1050m/ TDCY1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I <sub>F</sub> = 2 mA	TDCY1050m	I <sub>V</sub>		1.5		mcd
segment 1)							
		TDCY1060m	I <sub>V</sub>		1.5		mcd
	I <sub>F</sub> = 10 mA	TDCY1050m	I <sub>V</sub>	4.0	8.0		mcd
		TDCY1060m	I <sub>V</sub>	4.0	8.0		mcd
Luminous intensity of colon	I <sub>F</sub> = 2 mA	TDCY1050m	I <sub>V</sub>		0.4		mcd
		TDCY1060m	I <sub>V</sub>		0.4		mcd
	I <sub>F</sub> = 10 mA	TDCY1050m	I <sub>V</sub>	0.5	1.0		mcd
		TDCY1060m	I <sub>V</sub>	0.5	1.0		mcd
Dominant wavelength	I <sub>F</sub> = 20 mA		$\lambda_{d}$		589		nm
Peak wavelength	I <sub>F</sub> = 20 mA		$\lambda_{p}$		591		nm
Spectral bandwidth	I <sub>F</sub> = 20 mA		Δλ		15		nm
Forward voltage	I <sub>F</sub> = 20 mA		$V_{F}$		2.0	2.4	V
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>			10	μΑ

Note<sup>1)</sup>  $I_{Vmin}$  and  $I_{V}$  groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is  $\geq$  0.5, excluding decimal points and colon.





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#### Green

#### TDCG1050m/ TDCG1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I <sub>F</sub> = 2 mA	TDCG1050m	I <sub>V</sub>		1.0		mcd
segment 1)							
		TDCG1060m	I <sub>V</sub>		1.0		mcd
	I <sub>F</sub> = 10 mA	TDCG1050m	I <sub>V</sub>	2.8	4.0		mcd
		TDCG1060m	I <sub>V</sub>	2.8	4.0		mcd
Luminous intensity of colon	I <sub>F</sub> = 2 mA	TDCG1050m	I <sub>V</sub>		0.2		mcd
		TDCG1060m	I <sub>V</sub>		0.2		mcd
	I <sub>F</sub> = 10 mA	TDCG1050m	I <sub>V</sub>	0.5	1.2		mcd
		TDCG1060m	I <sub>V</sub>	0.5	1.2		mcd
Dominant wavelength	I <sub>F</sub> = 20 mA		$\lambda_{d}$		573		nm
Peak wavelength	I <sub>F</sub> = 20 mA		$\lambda_{p}$		575		nm
Spectral bandwidth	I <sub>F</sub> = 20 mA		Δλ		20		nm
Forward voltage	I <sub>F</sub> = 20 mA		$V_{F}$		2.0	2.4	V
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>			10	μА

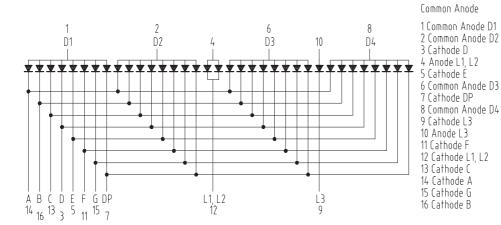
Note<sup>1)</sup>  $I_{Vmin}$  and  $I_{V}$  groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is  $\geq$  0.5, excluding decimal points and colon.

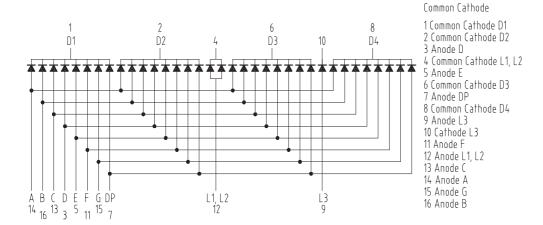
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# **Vishay Semiconductors**

# **Pinning**







Drawing-No.: 6.544-5332.01-4 Bl. 2

Issue: 1; 20.02.02

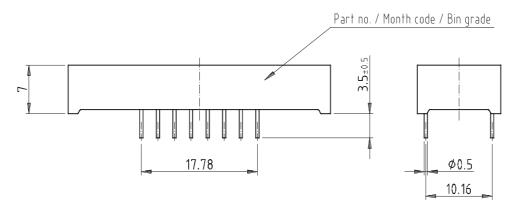
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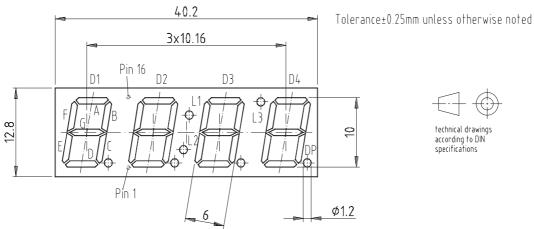
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# **Vishay Semiconductors**

# Package Dimensions in mm





Drawing-No.: 6.544-5332.01-4 Bl. 1

Issue: 3; 27.02.02

# **TDCG / R / Y10..m**

#### **Vishay Semiconductors**



## **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

#### We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

> Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

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